

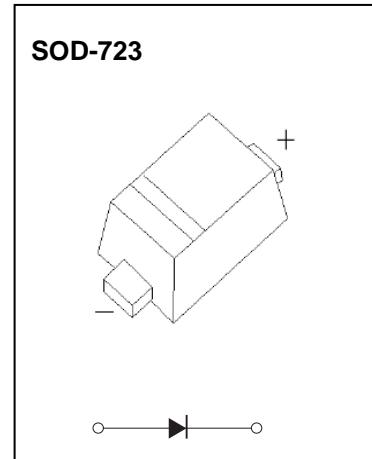


JIANGSU CHANGJIANG ELECTRONICS TECHNOLOGY CO., LTD

SOD-723 Plastic-Encapsulate Diodes

RB521G-30 Schottky barrier Diode**FEATURES**

- Small surface mounting type
- High reliability

**MARKING: F****Maximum Ratings and Electrical Characteristics, Single Diode @Ta=25°C**

Parameter	Symbol	Limit			Unit
DC reverse voltage	V_R	30			V
Mean rectifying current	I_o	100			mA
Peak forward surge current	I_{FSM}	1			A
Power dissipation	D_8	100			mW
Thermal Resistance Junction to Ambient	$\dot{F}_{>5}$	1000			°C/W
Junction temperature	T_j	125			°C
Storage temperature	T_{stg}	-55~+150			°C

Electrical Ratings @Ta=25°C

Parameter	Symbol	Min	Typ	Max	Unit	Conditions
Forward voltage	V_F			0.35	V	$I_F=10\text{mA}$
Reverse current	I_R			10	μA	$V_R=10\text{V}$